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August 2016

FPF1203 / FPF1203L / FPF1204 / FPF12045 IntelliMAX[™] Ultra-Small, Slew-Rate-Controlled Load Switch

Features

- 1.2 V to 5.5 V Input Voltage Operating Range
- Typical R_{ON}:
 - 45 m Ω at V_{IN}=5.5 V
 - 55 m Ω at V_{IN}=3.3 V
 - 90 m Ω at V_{IN}=1.8 V
 - 185 m Ω at V_{IN}=1.2 V
- Slew Rate Control with t_R:
 - FPF1203/FPF1203I/FPF1204: 100 µs
 - FPF12045: 2 µs
- Output Discharge Function on FPF1204 / 45
- Low <1.5 µA Quiescent Current
- ESD Protected: Above 7 kV HBM, 2 kV CDM
- GPIO / CMOS-Compatible Enable Circuitry
- 4-Bump, WLCSP 0.76 mm x 0.76 mm, 0.4 mm Pitch

Description

The FPF1203 / 03L / 04 / 45 are ultra-small integrated IntelliMAX[™] load switches with integrated P-channel switch and analog control features. Integrated slewrate control prevents inrush current and the resulting excessive voltage drop on the power rail. The input voltage range operates from 1.2 V to 5.5 V to provide power-disconnect capability for post-regulated power rails in portable and consumer products. The low shutoff current allows power designs to meet standby and off-power drain specifications.

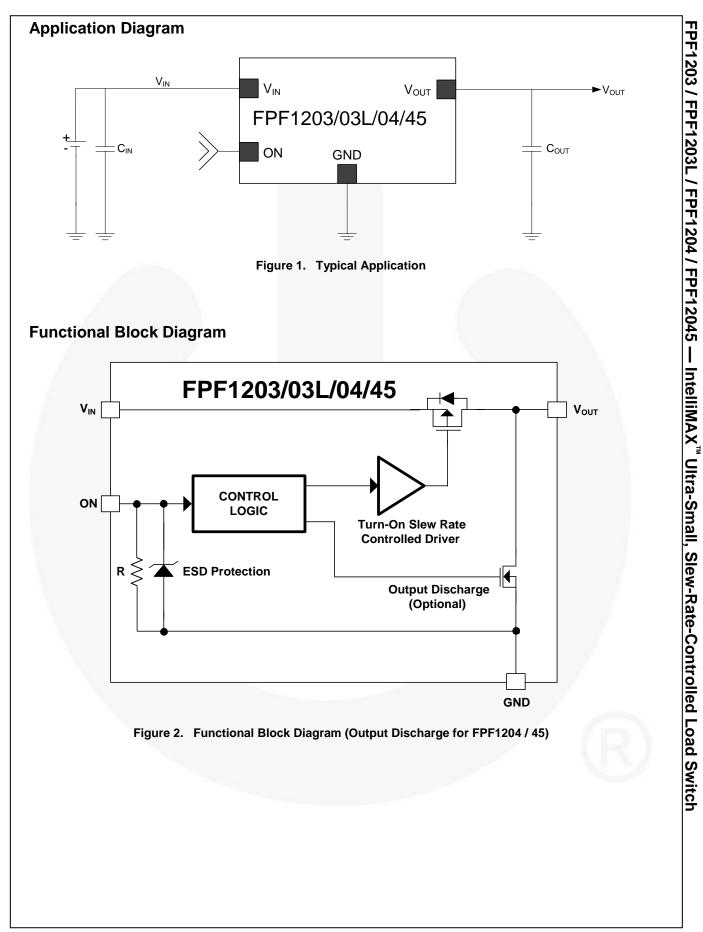
The FPF120x are controlled by a logic input (ON pin) compatible with standard CMOS GPIO circuitry found on Field Programmable Gate Array (FPGA) embedded processors. The FPF120x are available in 0.76 mm x 0.76 mm 4-bump WLCSP.

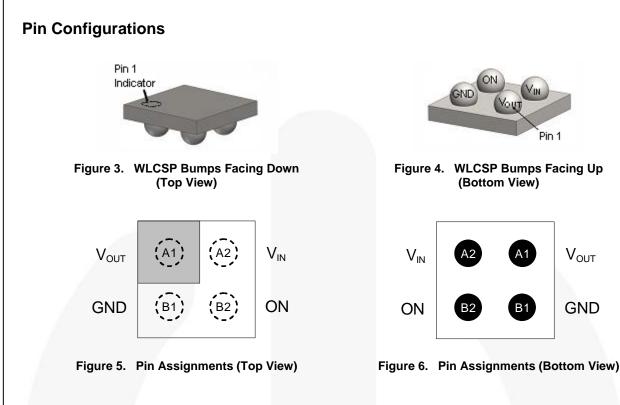
Applications

- Mobile Devices and Smart Phones
- Portable Media Devices
- Tablet PCs
- Advanced Notebook, UMPC, MID
- Portable Medical Devices
- GPS and Navigation Equipment

Ordering Information								
Part Number	Top Mark	Switch (Typical) at 3.3V _{IN}	Output Discharge	ON Pin Activity	t _R	Package		
FPF1203UCX	QL	55 mΩ	NA	Active HIGH	100 µs			
FPF1203LUCX	QP	55 mΩ	NA	Active LOW	100 µs			
FPF1204UCX	QM	55 mΩ	65 Ω	Active HIGH	100 µs	4-Bump, Wafer-Level Chip-		
FPF1204UCX_F013 (Amkor Assembly Only)	QM	55 mΩ	65 Ω	Active HIGH	100 µs	Scale Package (WLCSP), 0.76 mm x 0.76 mm,		
FPF1204BUCX (Backside Laminate)	QM	55 mΩ	65 Ω	Active HIGH	100 µs	0.4 mm Pitch		
FPF12045UCX	NC	55 mΩ	65 Ω	Active HIGH	2 µs			

a. Infamo





Pin Definitions

Pin #	Name	Description		
A1	Vout	Switch output		
A2	V _{IN}	Supply input: input to the power switch		
B1	GND	ound		
B2	ON	DN/OFF Control, active HIGH; FPF1203/04/45		
B2	ON	ON/OFF Control, active LOW; FPF1203L		

ON

(Bottom View)

R1

MD

R2

V_{IN}

Pin 1

V_{OUT}

GND

Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Symbol	Parameter			Max.	Unit
V _{IN}	V _{IN} , V _{OUT} , V _{ON} to GND			6.0	V
I _{SW}	Maximum Continuous Switch Current at Ambient Operating Temperature			2.2	А
PD	Power Dissipation at T _A =25°C			1.0	W
T _{STG}	Storage Temperature Range			+150	°C
	Thermal Resistance, Junction-to-Ambient	1S2P with One Thermal Via ⁽¹⁾		110	°C/W
Θ_{JA}	mermar Resistance, Junction-to-Ambient	1S2P without Thermal Via ⁽²⁾		95	
ESD Electrostatic Discharge Conshility (^{1,2}		Human Body Model, JESD22-A114	7		kV
ESD	Electrostatic Discharge Capability ^(1,2)	Charged Device Model, JESD22-C101	2		ΝV

Notes:

1. Measured using 2S2P JEDEC std. PCB.

2. Measured using 2S2P JEDEC PCB COLD PLATE Method.

Recommended Operating Conditions

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended operating conditions are specified to ensure optimal performance to the datasheet specifications. Fairchild does not recommend exceeding them or designing to Absolute Maximum Ratings.

Symbol	Parameter	Min.	Max.	Unit
V _{IN}	Input Voltage	1.2	5.5	V
TA	Ambient Operating Temperature	-40	+85	°C

Symbol	Parameter		Condition	Min.	Тур.	Max.	Unit
Basic Op	eration					1 1	
V _{IN}	Supply Voltage			1.2		5.5	V
	Off Supply	FPF1203/04/45	V _{ON} =GND, V _{OUT} =Open, V _{IN} =5.5 V		0.1	1.0	
$I_{Q(OFF)}$	Current	FPF1203L	V _{ON} =V _{IN} , V _{OUT} =Open, V _{IN} =5.5 V		1.0	2.0	μA
	Shutdown	FPF1203/04/45	V _{ON} =GND, V _{OUT} =GND		0.1	1.0	
I _{SD}	Current	FPF1203L	V _{ON} =V _{IN} , V _{OUT} =GND		1.2	3.0	μA
	Quiescent Current	FPF1203/04/45	I _{OUT} =0 mA, V _{ON=} V _{IN} , =5.5 V				μA
lq		FPF1203L	I _{OUT} =0 mA, V _{ON} =GND, V _{IN} = 5.5 V		0.1	1.5	
			V _{IN} =5.5 V, I _{OUT} =200 mA, T _A =25°C	-	45	55 ⁽³⁾	
			V _{IN} =3.3 V, I _{OUT} =200 mA, T _A =25°C	1	55	65 ⁽³⁾	mΩ
Ron	On Resistance		V _{IN} =1.8 V, I _{OUT} =200 mA, T _A =25°C		90	100 ⁽³⁾	
			V _{IN} =1.2 V, I _{OUT} =200 mA, T _A =25°C		185	220 ⁽³⁾	
			V _{IN} =1.8 V, I _{OUT} =200 mA, T _A =85°C ⁽³⁾			105	
R _{PD}	Output Discharge RPULL DOWN		V _{IN} =3.3 V, V _{ON} =OFF, I _{FORCE} =20 mA, T _A =25°C, FPF1204 / FPF12045		65	75	Ω
VIH	On Input Logic HIGH Voltage		V_{IN} =1.2 V to 5.5 V	1.15			V
V _{IL}	On Input Logic LOW Voltage		V_{IN} =1.2 V to 5.5 V			0.65	V
R _{ON_PD}	Pull-Down Resis	stance at ON Pin	V _{IN} =1.2 V to 5.5 V		8.3		MΩ
I _{ON}	On Input Leakag	ge	V _{ON} =V _{IN} or GND			1	μA
Dynamic	Characteristics					<u> </u>	
t _{DON}	Turn-On Delay ⁽⁴	4)			70		
t _R	V _{OUT} Rise Time	(4)			100		
t _{ON}	Turn-On Time ⁽⁶⁾		V _{IN} =3.3 V, R _L =10 Ω, C _L =0.1 μF,	1	170		
t _{DON}	Turn-On Delay ⁽⁴⁾		$T_{A}=25^{\circ}C, FPF12045$		2		μs
t _R	VOUT Rise Time	(4)			2		
t _{ON}	Turn-On Time ⁽⁶⁾		1		4		
t _{DOFF}	Turn-Off Delay ⁽⁴	1,5)			0.5		
t _F	V _{OUT} Fall Time ⁽⁴		V _{IN} =3.3 V, R _L =10 Ω, C _L =0.1 μF, T _A =25°C, FPF1203L		2.0		μs
t _{OFF}	Turn-Off Time ^{(5,}	7)	1A-23 0, 111 1203L		2.5		
t _{DOFF}	Turn-Off Delay ^(4,5) V _{OUT} Fall Time ^(4,5) Turn-Off Time ^(5,7)				6		-
t⊧			V _{IN} =3.3 V, R _L =500 Ω, C _L =0.1 μF, T _A =25°C, FPF1203L		115		μs
t _{OFF}			1A-20 0, 111 1200L		121		
t _{DOFF}	Turn-Off Delay ⁽⁴	1,5)			4.0		
t _F	V _{OUT} Fall Time ^(4,5)		V _{IN} =3.3 V, R _L =10 Ω, C _L =0.1 μF, T _A =25°C, FPF1203		2.9		μs
t _{OFF}	Turn-Off Time ^{(5,}	7)	1 _A -20 0, 111 1200		7.3		
t _{DOFF}	Turn-Off Delay ⁽⁴	1,5)			6		
t _F	V _{OUT} Fall Time ^(4,5)		V _{IN} =3.3 V, R _L =500 Ω, C _L =0.1 μF, T _A =25°C, FPF1203		115		μs
		T _A =25°C, FPF1203			121	<u> </u>	

Continued on the following page...

Electrical Characteristics

Unless otherwise noted, V_{IN} =1.2 V to 5.5 V and T_A =-40 to +85°C. Typical values are at V_{IN} =3.3 V and T_A =25°C.

Symbol	Parameter	Condition	Min.	Тур.	Max.	Unit
t _{DOFF}	Turn-Off Delay ^(4,5)			4.0		
t _F	V _{OUT} Fall Time ^(4,5)	V _{IN} =3.3 V, R _L =10 Ω, C _L =0.1 μF, T _A =25°C, FPF1204/45 ⁽⁵⁾		2.5		μs
t _{OFF}	Turn-Off Time ^(5,7)	1 <u>,</u> 20 0, 111120 // 10		6.5		
t _{DOFF}	Turn-Off Delay ^(4,5)			6		
t _F	V _{OUT} Fall Time ^(4,5)	V _{IN} =3.3 V, R _L =500Ω, C _L =0.1 μF, T _A =25°C, FPF1204/45 ⁽⁵⁾		11		μs
t _{OFF}	Turn-Off Time ^(5,7)	1, -20 0, 111120 , 10		17		

Notes:

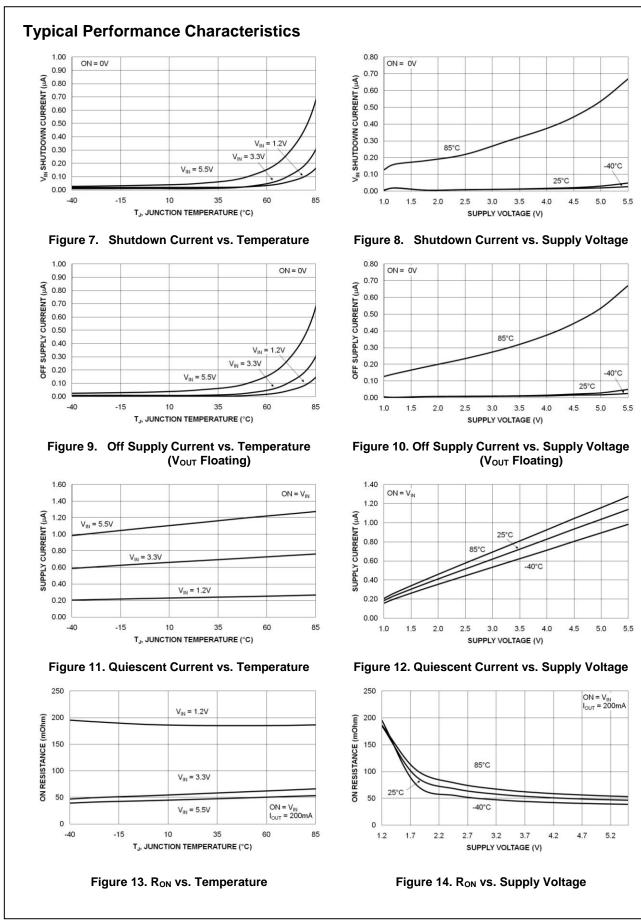
3. This parameter is guaranteed by design and characterization; not production tested.

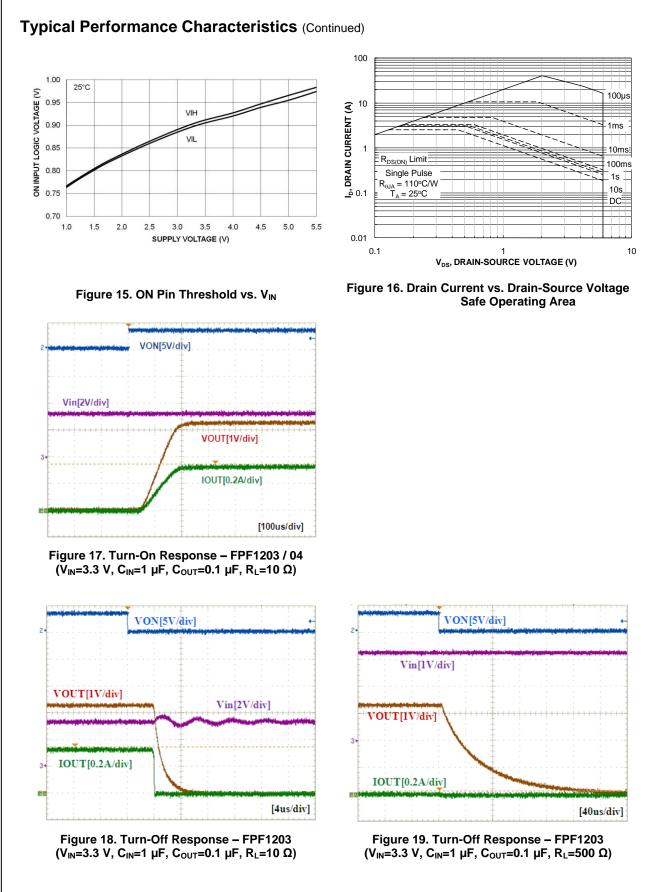
4. $t_{DON}/t_{DOFF}/t_R/t_F$ are defined in Figure 23.

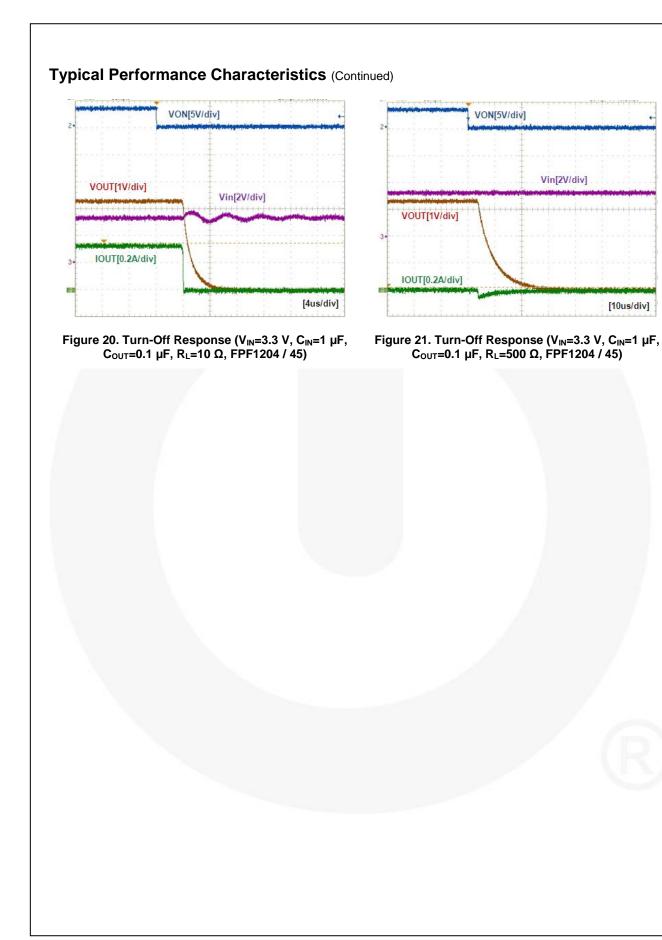
5. Output discharge enabled during off-state.

6. $t_{ON}=t_R + t_{DON}$

7. toff=tf + tDOFF.







FPF1203 / FPF1203L / FPF1204 / FPF12045 — IntelliMAXTM Ultra-Small, Slew-Rate-Controlled Load Switch

Operation and Application Description

The FPF1203 / 03L / 04 / 045 are low-R_{ON} P-channel load switches with controlled turn-on. The core of each device is a 55 m Ω P-channel MOSFET and controller capable of functioning over a wide input operating range of 1.2 to 5.5 V.

The FPF1204 / 45 contain a 65 Ω on-chip load resistor for quick output discharge when the switch is turned off.

The FPF12045 features a faster V_{OUT} Rise Time of 5 µs.

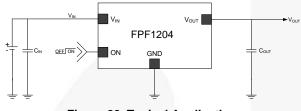


Figure 22. Typical Application

Input Capacitor

To limit the voltage drop on the input supply caused by transient inrush current when the switch turns on into a discharged load capacitor or short-circuit, a capacitor must be placed between the V_{IN} and GND pins. A 1 μ F ceramic capacitor, C_{IN}, placed close to the pins is usually sufficient. Higher-value C_{IN} can be used to reduce the voltage drop in higher-current applications.

Output Capacitor

A 0.1 μ F capacitor, C_{OUT}, should be placed between the V_{OUT} and GND pins. This capacitor prevents parasitic board inductance from forcing V_{OUT} below GND when the switch is on. C_{IN} greater than C_{OUT} is highly recommended. C_{OUT} greater than C_{IN} can cause V_{OUT} to exceed V_{IN} when the system supply is removed. This could result in current flow through the body diode from V_{OUT} to V_{IN}.

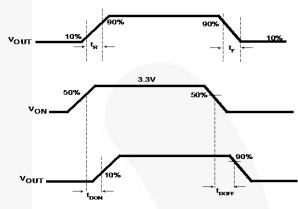


Figure 23. Timing Diagram for FPF1203/4/045

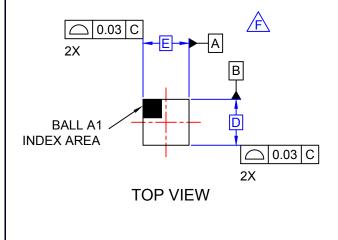
Board Layout

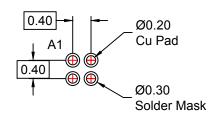
For best performance, traces should be as short as possible. To be most effective, input and output capacitors should be placed close to the device to minimize the effect of parasitic trace inductance on normal and short-circuit operation. Using wide traces or large copper planes for all pins (VIN, VOUT, ON, and GND) minimizes the parasitic electrical effects and the case-ambient thermal impedance. However, the VOUT pin should not connect directly to the battery source due to the discharge mechanism of the load switch.

The table below pertains to the Packaging information on the following page.

Product Dimensions

D	E	X	Y
760 μm ± 30 μm	760 μm ± 30 μm	0.180 mm± 0.018 µm	0.180 mm± 0.018 µm

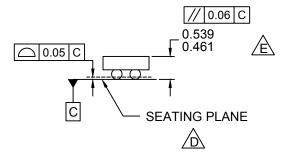




0.292±0.018

0.208±0.021

RECOMMENDED LAND PATTERN (NSMD PAD TYPE)



SIDE VIEWS

NOTES:

- A. NO JEDEC REGISTRATION APPLIES.
- B. DIMENSIONS ARE IN MILLIMETERS.
- C. DIMENSIONS AND TOLERANCE PER ASME Y14.5M, 1994.
- D. DATUM C IS DEFINED BY THE SPHERICAL CROWNS OF THE BALLS.
- /E.PACKAGE NOMINAL HEIGHT IS 500 MICRONS ±39 MICRONS (461-539 MICRONS).

F. FOR DIMENSIONS D, E, X, AND Y SEE PRODUCT DATASHEET.

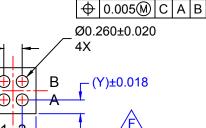
G. DRAWING FILNAME: MKT-UC004AFrev2.



BOTTOM VIEW

0.40

0.40



(X)±0.018

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